MOSFETs Silicon N-Channel MOS (U-MOSVI-H)

TK40P03M1

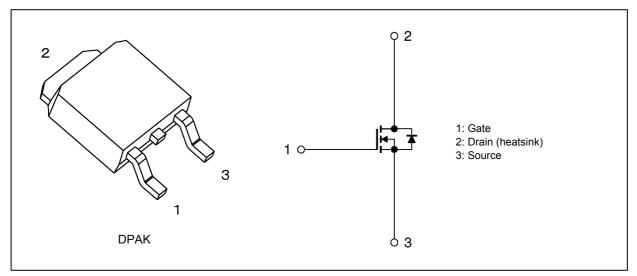
1. Applications

- DC-DC Converters
- Desktop PCs

2. Features

- (1) High-speed switching
- (2) Low gate charge: $Q_{SW} = 5.7 \text{ nC}$ (typ.)
- (3) Low drain-source on-resistance: $R_{DS(ON)} = 8.3 \text{ m}\Omega \text{ (typ.)} (V_{GS} = 10 \text{ V})$
- (4) Low leakage current: $I_{DSS} = 10 \ \mu A \ (max) \ (V_{DS} = 30 \ V)$
- (5) Enhancement mode: V_{th} = 1.3 to 2.3 V (V_{DS} = 10 V, I_{D} = 0.1 mA)

3. Packaging and Internal Circuit



4. Absolute Maximum Ratings (Note) ($T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics			Rating	Unit
Drain-source voltage		V _{DSS}	30	V
Gate-source voltage		V _{GSS}	±20	
Drain current (DC)	(Note 1)	I _D	40	A
Drain current (pulsed)	(Note 1)	I _{DP}	120	
Power dissipation (T _c = 25	5°C)	PD	33	W
Single-pulse avalanche energy	(Note 2)	E _{AS}	42	mJ
Avalanche current		I _{AR}	40	A
Channel temperature		T _{ch}	150	°C
Storage temperature		T _{stg}	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-case thermal resistance	R _{th(ch-c)}	3.78	°C/W
Channel-to-ambient thermal resistance	R _{th(ch-a)}	125	

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: V_DD = 24 V, T_ch = 25°C (initial), L = 20 μ H, R_G = 25 Ω , I_{AR} = 40 A

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

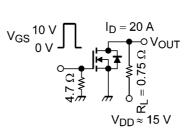
6. Electrical Characteristics

6.1. Static Characteristics (T_a = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I _{GSS}	V_{GS} = ±20 V, V_{DS} = 0 V	_	_	±0.1	μA
Drain cut-off current	I _{DSS}	V _{DS} = 30 V, V _{GS} = 0 V	—	_	10	
Drain-source breakdown voltage	V _{(BR)DSS}	I _D = 10 mA, V _{GS} = 0 V	30	—	—	V
	V _{(BR)DSX}	I _D = 10 mA, V _{GS} = -20 V	15	_	_	
Gate threshold voltage	V _{th}	V _{DS} = 10 V, I _D = 0.1 mA	1.3	_	2.3	
Drain-source on-resistance	R _{DS(ON)}	V _{GS} = 4.5 V, I _D = 20 A		11.1	14.4	mΩ
		V _{GS} = 10 V, I _D = 20 A		8.3	10.8	

6.2. Dynamic Characteristics ($T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C _{iss}	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz		1150	_	pF
Reverse transfer capacitance	C _{rss}]		85	_	
Output capacitance	C _{oss}]		260	_	
Gate resistance	r _g	V_{DS} = 10 V, V_{GS} = 0 V, f = 5 MHz	_	2.9	4.4	Ω
Switching time (rise time)	tr	See Figure 6.2.1.	_	15	_	ns
Switching time (turn-on time)	t _{on}]		21	_	
Switching time (fall time)	t _f]		14	_	
Switching time (turn-off time)	t _{off}	1		54		



Duty \leq 1%, t_w = 10 μ s

Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics ($T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus	Qg	$V_{DD} \approx 24$ V, V_{GS} = 10 V, I_D = 40 A	_	17.5	_	nC
gate-drain)		$V_{DD} \approx 24$ V, V_{GS} = 5 V, I_D = 40 A	—	9.4	—	
Gate-source charge 1	Q _{gs1}	$V_{DD} \approx 24$ V, V_{GS} = 10 V, I_D = 40 A	_	4.1	—	
Gate-drain charge	Q _{gd}		_	3.5	_	
Gate switch charge	Q _{SW}			5.7		

6.4. Source-Drain Characteristics ($T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Reverse drain current (pulsed) (1	Note 3)	I _{DRP}	_		_	120	А
Diode forward voltage		V_{DSF}	I _{DR} = 40 A, V _{GS} = 0 V	_	_	-1.2	V

Note 3: Ensure that the channel temperature does not exceed 150°C.

7. Marking

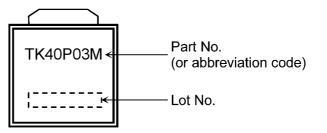
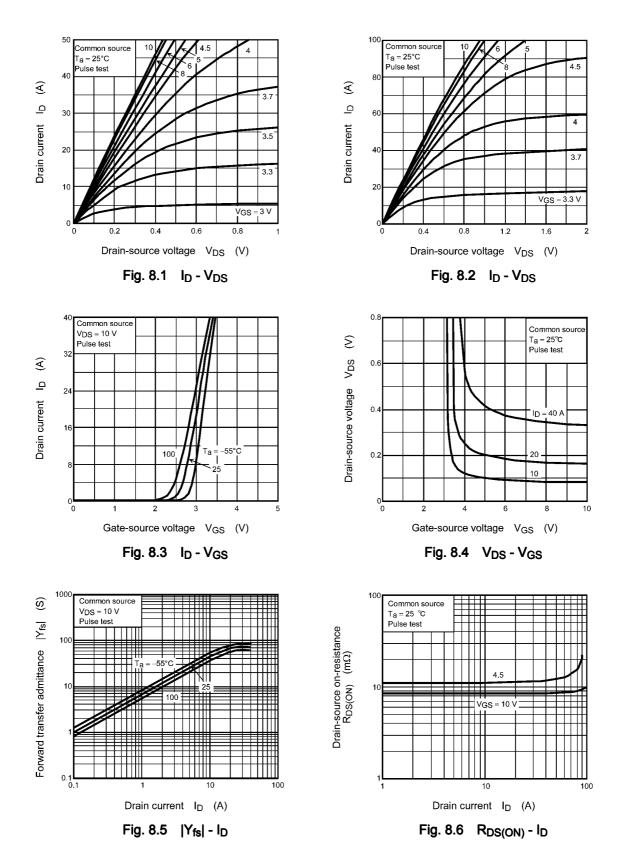


Fig. 7.1 Marking

8. Characteristics Curves (Note)



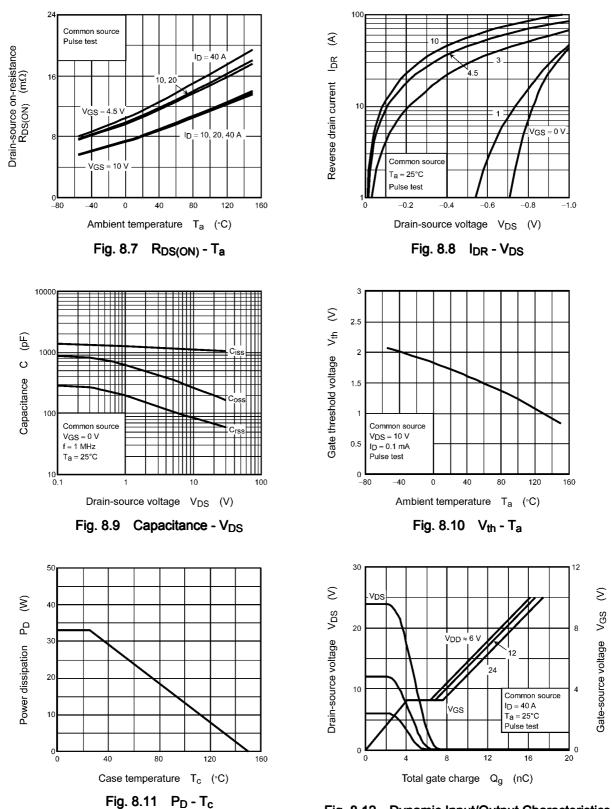


Fig. 8.12 Dynamic Input/Output Characteristics

(Guaranteed Maximum)

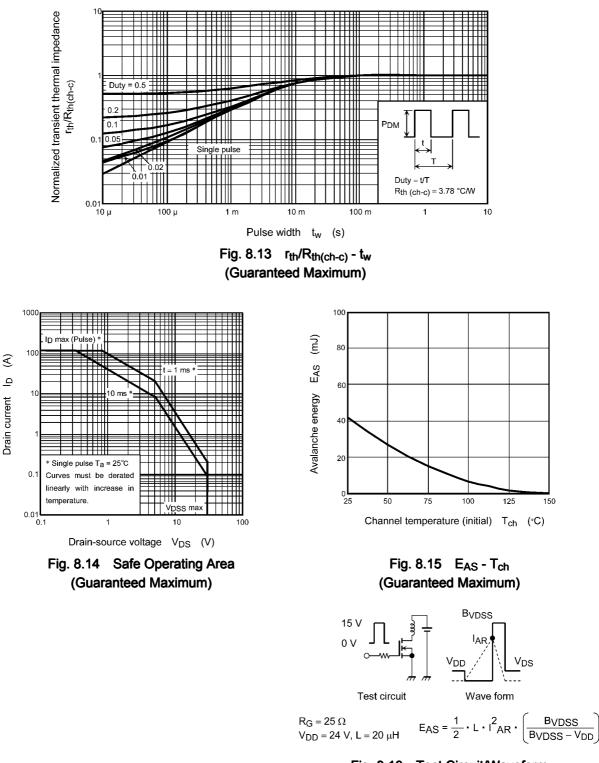


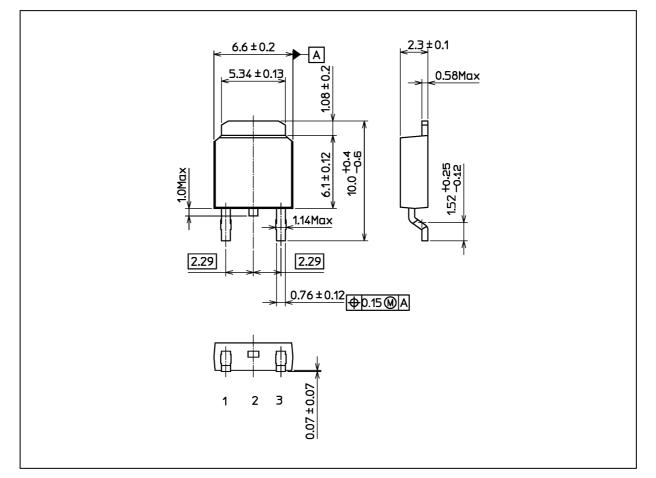
Fig. 8.16 Test Circuit/Waveform

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

TK40P03M1

Package Dimensions

Unit: mm



Weight: 0.36 g (typ.)

	Package Name(s)
TOSHIBA: 2-7K1S	
Nickname: DPAK	

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